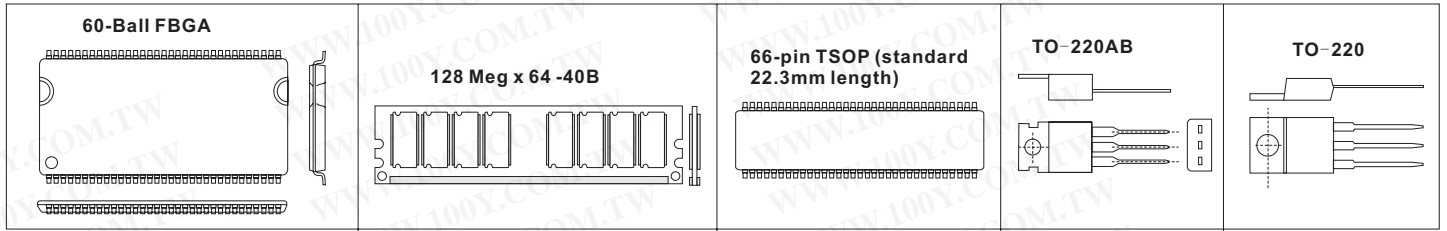


Semiconductors-Discretes

MTP~ Series J-FET Transistors

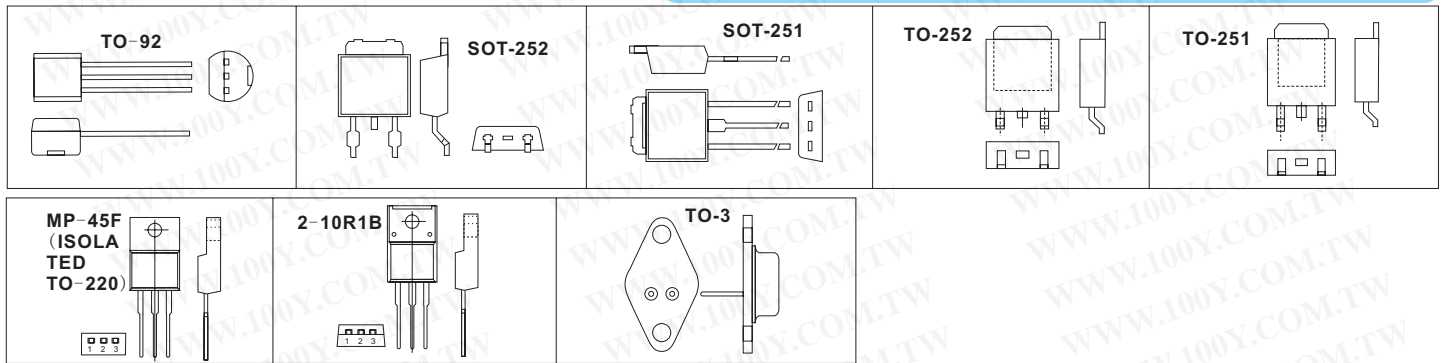
Detailed product specifications are available on: us.100y.com.tw



Part No.	Product No.	Manufacturer	Description	N/P Ch.	Pins/Package	Pd(max)	Vds	Vgss	Id(max)	Mode
41997	MT16VDDT12864AG-40B		DDR SDRAM UNBUFFERED DIMM		128 Meg x 64 -40B					1GB
41984	MT46V16M16FG-6		256M DDR SDRAM Component		60-Ball FBGA (8mm x 14mm)		0.45			60-Ball
41973	MT46V32M16FN-6		512M DDR SDRAM Component		60-Ball FBGA (10 x 12.5mm)					FN
42003	MT46V32M16TG-75		512M DDR SDRAM		66-pin TSOP (standard 22.3mm length)					512Mb
40222	MTP12P10	ON-Semi.	Power MOSFET 12 Amps, 100 Volts	P-Ch.	TO-220AB	75W	100V		12A	
35500	MTP2P50E	ON-Semi.	Power MOSFET 2 Amps, 500 Volts	P	TO-220AB	75W	500V	20V	2.0A	
13148	MTP3055V		TRANSISTOR	N	3P/TO-220	48W	60V	20V	12A	
39719	MTP3N120E	MOTOROLA	TMOS POWER FET N-Ch. 3.0A 1200V	N	TO-220AB	125W	1200V		3A	
39394	MTP50N06V	ON-Semi.	Power MOSFET 42 Amps, 60 Volts	N	TO-220AB	125W	60V		42A	
35501	MTP50P03HDL	ON-Semi.	Power MOSFET 50 Amps, 30 Volts, Logic Level	P	TO-220AB	125W	30V	15V	50A	
35502	MTP60N06HD	ON-Semi.	Power MOSFET 60 Amps, 60 Volts	N	TO-220AB	150W	60V	20V	60A	

2SJ~ Series Transistors

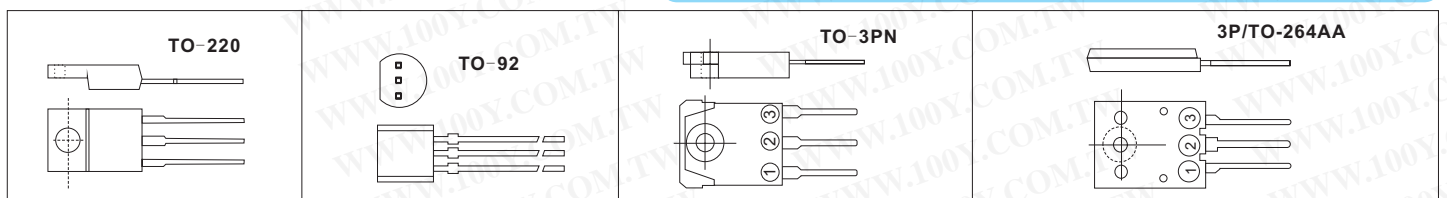
Detailed product specifications are available on: us.100y.com.tw



Part No.	Product No.	Manufacturer	Description	N/P Ch.	Pins/Package	Pd(max)	Vds	Vgss	Id(max)	Mode
18465	2SJ108	TOSHIBA	JFET		3P/TO-92	200mW	25V		-10mA	
36427	2SJ148	TOSHIBA	MOS FIELD EFFECT TRANSISTOR	P	3P/TO-92	400mW	-60V	±20V	-200mA	TO-92
46066	2SJ246	HITACHI	MOSFET	P	SOT-252	20W	30V	±20V	7A	
14864	2SJ299L	HITACHI	MOSFET	P	3P/TO-251(I-PAK)	20W		-20V	-5A	
31990	2SJ333	NEC	SWITCHING P-CHANNEL POWER MOSFET INDUSTRIAL USE		TO-252					
35860	2SJ334	TOSHIBA	P CHANNEL MOS	P	SC-67	45W	-60V	20V	-30A	
29147	2SJ448	FUJITSU	MOSFET		TO-220F			+/-25V	+/-16A	
35861	2SJ50	HITACHI	LOW FREQUENCY POWER AMPLIFIER	P	TO-3	100W	-160V	14V	-7A	

2SK~ Series Power MOSFET

Detailed product specifications are available on: us.100y.com.tw



Part No.	Product No.	Manufacturer	Description	N/P Ch.	Pins/Package	Pd(max)	Vds	Vgss	Id(max)	Rds(on)(max.) Ω
14862	2SJ449	NEC	MOS field effect transistor	P	3P/TO-220	35W	250V	±30V	6A	TO-220
40034	2SJ74	Fairchild	P channel field effect transistor	P-Ch	TO-92	400mW	-10 V	25V	-1 mA	
15942	2SK1017	Fuji Elect	N-channel silicon power MOSFET	N	3P/TO-3PN	150W	450V		20A	
15662	2SK1020	FUJITSU	N-channel silicon power MOSFET	N	3P/TO-264AA	300W	500V	±30V	30A	
15569	2SK1045	MITSUBISHI	Transistor	N	3P/TO-3PN	150W	8000V	±30V	5A	
20243	2SK1061	TOSHIBA	N channel field effect transistor	N-Ch.	3P/TO-92	300mW	60V	+/-20V	200mA	0.6Ω
15657	2SK1081	Fairchild	N-channel silicon power MOSFET	N	TO-3P(N)	125W	800V	±30V	7A	

